Signatures of polaronic excitations in quasi-one-dim ensional LaT iO 3:41

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The optical properties of quasi-one-dimensional metallic LaT iD $_{3:41}$ are studied for the polarization along the a and b axes. W ith decreasing temperature modes appear along both directions suggestive for a phase transition. The broadness of these modes along the conducting axis might be due to the coupling of the phonons to low -energy electronic excitations across an energy gap. We observe a pronounced midinfrared band with a temperature dependence consistent with (interacting) polaron models. The polaronic picture is corroborated by the presence of strong electron-phonon coupling and the temperature dependence of the dc conductivity.

Titanium oxide compounds have been investigated extensively over the last decades, at the latest since the discovery of high-T_c superconductivity in the cuprates, to study the role of electronic correlations and to explore the doping induced transition from a M ott insulator to a m etal, like, e.g., in La_{1 v} Sr_v T iO $_3$.^{1;2} O f further interest are the titanates because of the proposed polaronic nature of their charge carriers. For example, the existence of small polarons in La1 TiO3 was shown by dc resistivity and therm celectric powerm easurem ents.2;3 Signatures of polaronic carriers were also found in the optical response of T iD $_2$, B a T iD $_3$, and SrT iD $_3$ in the form of a midin framed (M IR) band.^{4 {8} Since a M IR band of (spin-) polaronic origin at 1000 cm⁻¹ was also found in several cuprates^{9 {12} it seems to be a characteristic feature of this class of compounds for low doping as well. The proposal that (bi)polaronsm ight play a major role for the high-T_c superconductivity¹³ stimulated a vast amount of experim ental investigations on this issue.

On the other hand, the nature of the polaronic carriers in the titanates is still under discussion. In this paper we present the optical properties of another titanium oxide compound, LaT iO $_{3:41}$, to search for polaronic signatures and test their compatibility with the existing models. Indeed, we nd a strong M IR band in the optical response showing a strong temperature dependence. A particular property of LaT iO $_{3:41}$ is its quasione-dimensional (quasi-1D) m etallic character which was recently found by resistivity measurements.¹⁴ It is interesting to note that a M IR band was also observed for a variety of organic and anorganic quasi-1D m etals, like TTF-TCNQ,¹⁵ the Bechgaard salts,¹⁶ -N $a_{0:33}V_2O_5$,¹⁷ and SrN bO $_{3:41}$.¹⁸ W hether this band is related to the 1D transport and, in particular, is of (vibrational or spin-) polaronic origin, are open questions which we want to address here.

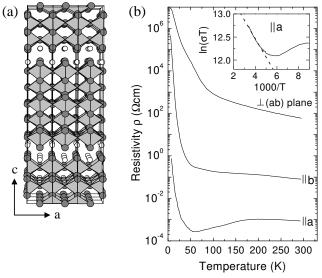


FIG.1. (a) Projection along the b axis of the schematic LaT $\dot{D}_{3:4}$ crystal structure. The T \dot{D}_6 octahedra (light grey) are connected continuously via their apical sites forming 1D chains along a (grey circles: 0 atom s, white circles: La atom s; T i atom s hidden within the T \dot{D}_6 octahedra). (b) dc resistivity of LaT $\dot{D}_{3:41}$ versus temperature T along the three crystal axes. Inset: Fit (dashed line) of T between 200 and 300 K according to Eq. (2) for sm all polaron hopping.

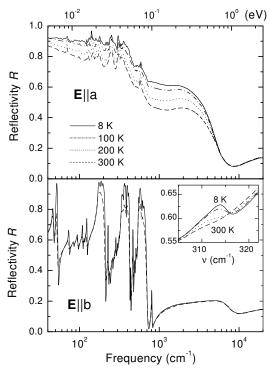


FIG.2. Re ectivity R of LaT iD $_{3:41}$ for E ka and E kb. Inset: D etailed tem perature dependence of a phonon m ode for E kb appearing below 200 K.

Single crystals of LaT iO 3:41 were grown by a oating zone melting process;¹⁴ the oxygen content was determined by therm ogravimetry. The layered crystal structure [see Fig. 1(a)] is built from slabs of distorted TiO_6 octahedra parallel to the (a,b) plane; it is monoclinic with lattice constants a= 7.86 A, b= 5.53 A, c=31.48 A, and =97.1. Like for the closely related compound SrNbO 3:41 a characteristic property of the structure are the 1D chains of octahedra along the a axis.¹⁴ LaT iO 3:41 belongs to the hom ologous series $La_n T i_n O_{3n+2}$ which exhibits a very rich phase diagram :¹⁴ stoichiom etric LaTiO $_{3:00}$ (n=1 , Ti $3d^1)$ is an antiferrom agnetic M ott insulator, while for o -stoichiom etric ТіОз m etallic character of polaronic type was La₁ observed,^{2;3} LaT iO_x for 3.00 < x < 3.50 is conducting,¹⁴ and in particular LaT iD 3:41 (T i 3d^{0:18}) shows a quasi-1D m etallic behavior, ¹⁴ LaT iO $_{3:50}$ (n=4, Ti 3d⁰) is a ferroelectric band insulator.¹⁹ The dc resistivity as a function oftem perature T depicted in Fig.1(b) dem onstrates the strongly an isotropic character of LaT iO 3:41. A long the b direction and perpendicular to the (a,b) plane the com pound shows a sem iconducting behavior, whereas along the a direction the T dependence is more complicated: Below 60 K a rises steeply with decreasing T, between 60 and 200 K its T dependence is m etallike, and above 200 Κ a slightly decreases with increasing T. This temperature dependence will be discussed in more detail later.

N ear-norm al incidence re ectivity spectra were measured from 40 to 6000 cm $^1\,$ (5 m eV-0.74 eV) utilizing a Fourier-transform spectrom eter equipped with an ultra-

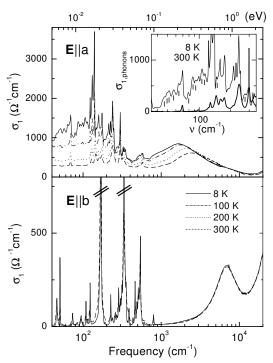


FIG.3. Optical conductivity $_1$ of LaT iO $_{3:41}$ for E ka and E kb. Inset: P honon contribution $_{1,\text{phonons}}$ to $_1$ for E ka from 35 to 350 cm 1 , obtained by subtracting the D rude term and the M IR band (from the D rude-Lorentz t) from the measured spectrum; ticks indicate the broad modes which appear below 100 K.

stable optical cryostat. To obtain absolute re ectivities the spectra were divided by the re ectivity spectra of a gold Im recorded at the sam e set of tem peratures, where the Im was deposited in situ on the sam ple. Since no tem perature dependence was found above 6000 cm⁻¹, the spectra were extended to 36 000 cm⁻¹ by the room - tem perature (RT) re ectivity data recorded with a variable angle spectroscopic ellipsom eter. Each re ectivity spectrum was extrapolated to low and high frequencies according to a D rude-Lorentz t; from the subsequent K ram ers-K ronig transform ation the phase of the re ection coe cient and thus the com plex dielectric function could be obtained.

The polarization-dependent re ectivity spectra R (!) of LaT iO $_{3:41}$ for several temperatures are shown in Fig. 2. They clearly demonstrate its quasi-1D m etallic character: For the polarization E ka, i.e., along the chains, we

nd a metallic behavior with a high rectivity at low frequencies and a sharp plasm a edge (! $_{\rm p}$ 3600 cm 1), while the overall low rectivity for E kb indicates an insulating character. The optical conductivity $_1$ (!) is presented in F ig. 3. For E kb no electronic absorption is observed in the far infrared (FIR); the spectrum below 1000 cm 1 consists of a large num ber of phonon lines, and the onset of interband transitions is found above 1000 cm 1 . A long the chains $_1$ consists of a D nude peak superim posed by vibrational lines and a pronounced M IR band.²⁰ W ith

decreasing tem perature we observe two m a jor changes in the E ka conductivity: (i) in the FIR region, between 50 and 300 cm⁻¹, modes (indicated by ticks in the inset of Fig. 3) possibly of vibrational origin appear below 100 K which are broader than the others, and (ii) the M IR band, located around 2500 cm⁻¹ at RT, continuously shifts to low er frequencies and its intensity increases; besides, an additional feature appears around 940 cm⁻¹. The changes are illustrated by the normalized di erence,

$$_1(!;T) = [_1(!;T) \quad _1(!;300K)] = _1(!;300K); (1)$$

shown in Fig.4. In the FIR, below 150 cm 1 , for T 100 K $_1$ (!) has slope zero and it increases with decreasing T due to the increase of $_{\rm dc}$; but below 100 K the slope clearly changes and in particular for 45{100 cm 1

1 increases strongly, indicating additional excitations in this frequency range.

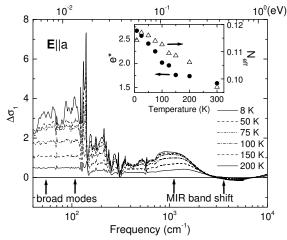


FIG.4. Normalized di erence $_1$ [Eq. (1)] of LaT iO $_{3:41}$ for E ka, illustrating the appearance of broad m odes and the M IR band shift with decreasing tem perature. Inset: E ective charge e of the phonon m odes and e ective carrier number N $_{\rm e}$ per Tiatom of the M IR band as a function of tem perature.

To quantify these changes we tted the E ka conductivity spectra with the Drude-Lorentz model. The M IR band was modelled by two Lorentzian functions. As an example we show the t for the RT spectrum in Fig. 5. This way we were able to extract the various contributions (D rude peak, \phonon" m odes, M IR band) for each temperature. From the spectral weights we calculated the e ective number of carriers (per Tiatom) for each contribution according to N $_{\rm e}~$ = m 1 (!)d!, where m $_{e}$ is the free elec- $[2m_eV = (e^2)] = 20_0^{1m}$ tron m ass, and V the unit cell volum e (containing 20 formula units). The upper integration limit !m was set to 15000 cm 1 , where the onset of the interband transitions is located. As is shown in the inset of Fig. 4, the e ective carrier number of the MIR absorption increases as the tem perature decreases, but below 75 K a saturation sets in. From the integrated intensities of the phonon modes

and by using the ionic charges of the atom swe calculated the e ective charge e according to the sum rule.²¹ The tem perature dependence of e (inset of Fig. 4) illustrates the substantial spectral weight grow th of the m odes with decreasing tem perature.

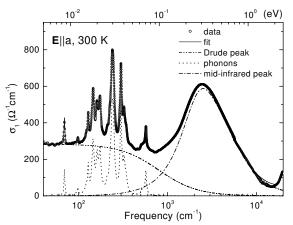


FIG.5. Fit of the RT conductivity $_1$ of LaT iO $_{3:41}$ with the D rude-Lorentz m odel.

W e now want to discuss the observed changes in the optical conductivity in more detail. (i) The appearance of vibrational modes in general suggests a breaking of the crystal symmetry. Some of the new modes for E ka are already very weakly present in the 125-K spectrum, but the substantial growth of their spectral weight sets in below 100 K. The occurrence of a phase transition in LaT iD 3:41 is corroborated by the developm ent of ten phonon lines for E kb with decreasing temperature (an example is shown in the inset of Fig. 2). A remarkable nding is the broadness of the new lines along the conducting a axis (see inset of Fig. 3) which m ight be due to the coupling of the phonons to electronic excitations. These low energy excitations m ight be excitations across an energy gap at E $_{\rm F}\,$ which develops below 100 K due to the phase transition. A coupling of the phonons to these excitations could also explain their signi cant spectral weight grow th below this tem perature. Since the broad modes appear at frequencies above 50 cm^{-1} , one could estimate the size of the gap to 6 m eV. The appearance of strong m odes along the m etallic axis caused by a coupling of phonon bands to the electronic density was in fact predicted by Rice²² when considering organic linear-chain conductors which undergo a chargedensity wave transition. For LaT iO 3:41 the presence of strong electron-phonon coupling is indicated by the enhanced e ective charge e = 1.6 at RT (see inset of Fig. 4) compared to the value e = 1 if there is no coupling. In general, the interaction between a discrete level and a continuum of states gives rise to asymmetric peaks in the excitation spectra.²³ Unfortunately, the large electronic background (D rude contribution) and the strong overlap of the modes render a line-shape analysis and thus a proof of the asym m etry of the new modes in LaT iO 3:41

di cult.

W ithin this scenario two open questions remain, however: First, the dc resistivity of LaT iO 3:41 shows no anom aly and thus no clear signature of a phase transition over the whole measured temperature range; a possible explanation could be the small number of carriers involved. Second, there is no direct evidence in the optical conductivity spectrum for excitations across an energy gap. Based on the present experimental results the occurrence of a phase transition therefore remains speculative. A dditional experimental investigations, for instance x-ray di raction or neutron-scattering measurements at low temperature, would be needed to clarify this issue.

(ii) The strong temperature dependence of the MIR band, namely its shift to lower frequencies and intensity increase for decreasing T with a saturation at a speci c tem perature, renders an interpretation of the band in terms of interband transitions unlikely. The observed evolution with temperature is similar to that of the MIR absorption in the cuprate superconductors which was attributed to polaronic excitations.^{10;11} The form ation of polarons in LaT iO 3:41 is corroborated by the presence of strong electron-phonon coupling indicated by the enhanced e ective charge e. A tem peraturedependent M IR band was also found for the nickelates $La_{2 \times} Sr_{x} N i O_{4+}$, where it was explained by photonassisted hopping of small polarons;^{24;25} photons in the M IR range excite self-trapped carriers from a localized state to localized states at neighboring sites, and the absorption is peaked at an energy twice the polaron binding energy E_P .²⁶ The position of the M IR band thus provides an estimate of E_P , which yields E_P h!=2 155 m eV for LaT iO $_{3:41}$ at RT.A conduction mechanism due to the hopping of sm all polarons, as suggested by the existence of a tem perature-dependent M IR band, is corroborated by the T dependence of a (see Fig. 1): Starting from the lowest tem perature, the steep drop of a denotes the therm alactivation of charge carriers. At 60 K the carriers are free and with further tem perature increase a rises since the carriers are increasingly scattered by phonons; m etallic transport is observed. The decrease of a above 200 K indicates that the contribution due to hopping of polaronic carriers prevails. For the dc conductivity (T) due to sm all polaron hopping one expects the therm ally activated form²⁷

T (T) / exp[
$$E_{H} = (k_{B} T)];$$
 (2)

where $E_{\rm H}$ is the hopping energy; the disorder energy is om itted since it is negligibly small compared to $E_{\rm H}$ in crystalline bulk materials. In the range 200-300 K $_{\rm a}$ (T) can be tted according to Eq. (2) (see inset of Fig. 1) which yields $E_{\rm H}$ 35 meV. This therm all activation energy is a factor of 2.2 sm aller than the activation energy $E_{\rm A} = E_{\rm P} = 2$ 78 meV,²⁷ obtained from our optical data; such a discrepancy between the therm all and opticall calcivation energies is expected since in the therm ally activated process the lattice has time to relax and $E_{\rm P}$ is thus reduced.

On the other hand, the temperature dependence of the MIR band in LaTiO_{3:41} { the softening with decreasing tem perature { is not com patible with a noncorrelated sm all polaron m odel for strong electron-phonon coupling.^{4;24;28} In the case of the high-T_c cuprate superconductors the M IR band softening was interpreted in term s of large polaron m odels including polaron-polaron interactions. 11;29 {31 A di erent approach was recently used by Fratini et al.³² who considered sm all polaron absorption for interm ediate electron-phonon coupling: Their calculated optical conductivity exhibits a noticeable transfer of spectral weight from high to low frequencies with decreasing tem perature, like we observe in LaT iO 3:41. Besides, the calculated spectra show anom alous peaks at frequencies com parable to the phonon frequencies with a strongly temperature-dependent intensity. These peaks, denoted as \polaron interband transitions", are purely electronic in nature and due to transitions between di erent subbands in the polaron excitation spectrum. They might serve as an alternative explanation for the broad peaks found in LaT iO 3:41 along the conducting direction.

W hether one of these polaron models actually applies to LaT iO 3:41, m ay be judged from a detailed com parison of the observed features (MIR absorption features, broad modes) to the theoretical absorption spectra, thereby considering that not only vibrational but also spin degrees of freedom could be involved in the polaron form ation, as it was proposed for other m aterials with strong electronic correlations like the cuprates¹² or the manganites.³³ The clari cation of these issues is of general in portance, since a band in the M IR frequency range is a characteristic feature in the optical spectrum of quasi-1D conductors.³⁴ A coording to the present results for LaT iO 3:41 the M IR band contains important information on the transport mechanism in quasi-1D systems and the careful study of its tem perature and doping dependence is therefore worthwhile.

In sum m ary, we studied the polarization dependent optical response of quasi-1D m etallic LaT iO 3:41 as a function oftem perature. W ith decreasing tem perature m odes appear along both studied crystal axes suggestive for a phase transition. The new modes found along the conducting direction a below 100 K are broader than the other modes, which might be caused by the coupling of the phonons to low-energy electronic excitations across an energy gap. The E ka conductivity spectrum contains a pronounced M IR band whose tem perature dependence is similar to that of the MIR absorption in the cuprate superconductors and consistent with (interacting) polaron models. The polaron form ation in LaT iO 3:41 is corroborated by the presence of strong electron-phonon coupling and the tem perature dependence of the dc conductivity. The ndings for LaTiO3:41 suggest the general in portance of polaronic quasiparticles for the transport m echanism in quasi-1D conductors.

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